

HIGH FREQUENCY SYNCHRONOUS PWM BUCK CONTROLLER WITH POWER GOOD OUTPUT

Features

- Internal 600kHz Oscillator (300kHz "A version")
- Operates with Single 5V or 12V Supply
- Programmable Over Current Protection
- Hiccup Current Limit Using MOSFET $R_{DS(on)}$ sensing
- Precision Reference Voltage (0.6V)
- Programmable Soft-Start
- Programmable PGood output
- Pre-Bias Start-up
- Thermal Protection
- 12-Lead MLP Package

Applications

- Distributed Point-of-Loads
- Embedded Systems
- Storage Systems
- DDR Applications
- Graphics Cards
- Computing Peripheral Voltage Regulators
- General DC-DC Converters

Description

The IR3629/IR3629A is a PWM controller designed for high performance synchronous Buck DC/DC applications. The IR3629/IR3629A drives a pair of external N-MOSFETs using a fixed 600kHz (300kHz "A version") switching frequency allowing the use of small external components. The output voltage can be precisely regulated using the internal 0.6V reference voltage for low voltage applications. Protection such as Pre-Bias startup, hiccup current limit and thermal shutdown provide the required system level security in the event of fault conditions.

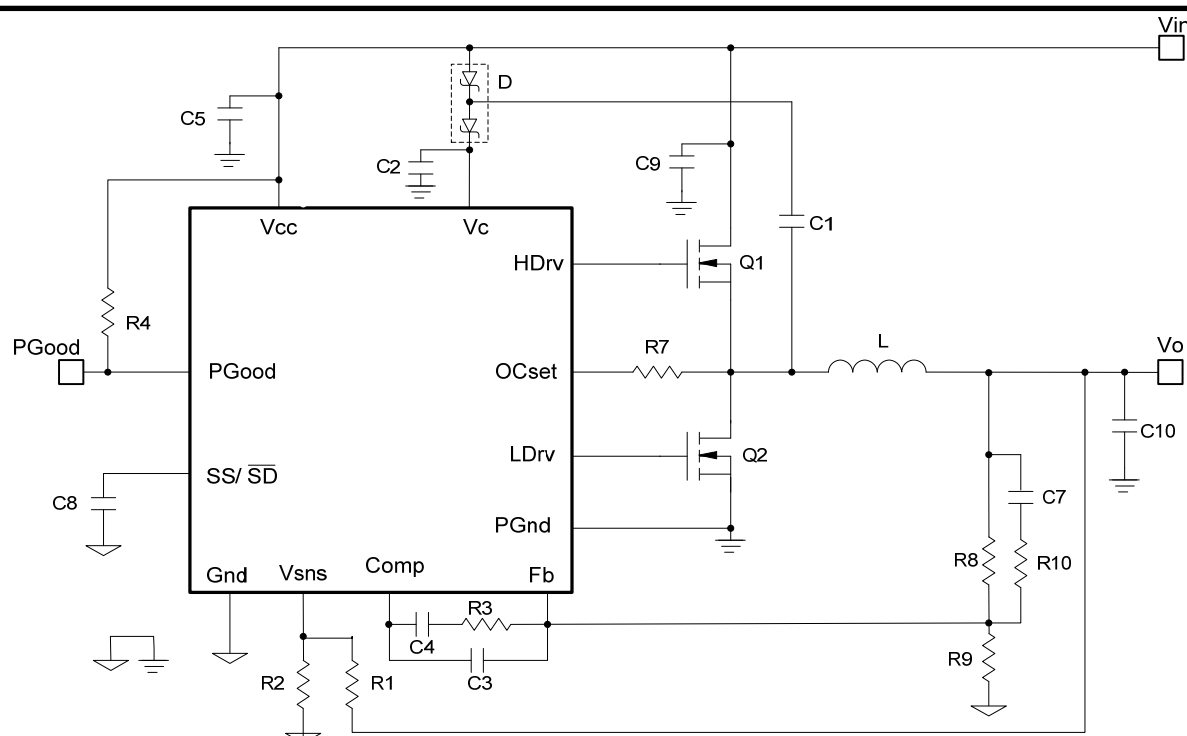


Fig. 1: Typical application Circuit

ORDERING INFORMATION

PKG DESIG	PACKAGE DESCRIPTION	PIN COUNT	PARTS PER TUBE	PARTS PER REEL	T&R ORIENTATION
M	IR3629/IR3629AMPBF	12	122	-----	
M	IR3629/IR3629AMTRPBF	12	-----	3000	Figure A

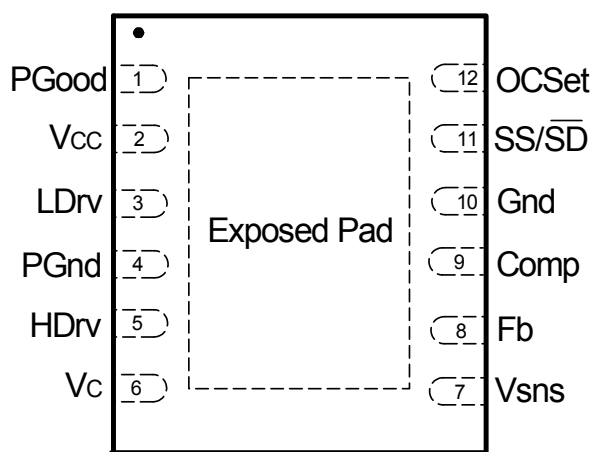
ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to GND)

- Vcc Supply Voltage -0.5V to 16V
- Vc Supply Voltage -0.5V to 30V
- PGood -0.5V to 16V
- Fb, Comp, SS -0.3V to 3.5V
- OCset 10mA
- AGnd to PGnd -0.3V to +0.3V
- Storage Temperature Range -65°C To 150°C
- Operating Junction Temperature Range -40°C To 150°C
- ESD Classification JEDEC, JESD22-A114
- Moisture Sensitivity Level JEDEC Level 2 @ 260°C

Caution: Stresses beyond those listed under “Absolute Maximum Rating” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to “Absolute Maximum Rating” conditions for extended periods may affect device reliability.

Package Information



12-Lead MLPD, 3x4mm

$$\theta_{JA} = 30^{\circ} \text{ C/W} *$$

$$\theta_{JC} = 2^{\circ} \text{ C/W}$$

*Exposed pad on underside is connected to a copper pad through vias for 4-layer PCB board design

The schematic diagram illustrates the internal control logic of the LT8602 buck converter. Key components and their connections include:

- Bias Generator:** Provides a 3V reference for the error amplifier and other internal blocks.
- Thermal Shutdown:** A block that monitors temperature and can trigger a shutdown.
- Error Amplifier:** Receives feedback from the output (Vc) and the sense resistor (Vsns) to regulate the output voltage.
- PWM Comp (Pulse Width Modulation Comparator):** Compares the error amplifier output with a sawtooth ramp from the oscillator to generate a PWM signal.
- PWM Latch:** A latch that stores the PWM signal and provides a reset domain (Reset Dom) signal.
- Oscillator:** Generates a 600kHz ramp (IR3629) and a 300kHz square wave (IR3629A).
- Pre-Bias Latch:** A latch that stores the pre-bias signal and provides a reset domain (Reset Dom) signal.
- OCen (Overcurrent Enable):** A block that generates an overcurrent enable signal based on the sense resistor voltage (Vsns) and the output current (LDrv).
- OCSet (Overcurrent Setpoint):** A block that sets the overcurrent threshold based on the sense resistor voltage (Vsns) and the output current (LDrv).
- SS (Soft Start):** A block that controls the soft start of the converter.
- POR (Power-On Reset):** A block that generates a power-on reset signal.
- OC (Overcurrent Protection):** A block that generates an overcurrent protection signal.
- OCSet (Overcurrent Setpoint):** A block that sets the overcurrent threshold.
- OCen (Overcurrent Enable):** A block that generates an overcurrent enable signal.
- OCSet (Overcurrent Setpoint):** A block that sets the overcurrent threshold.
- OCen (Overcurrent Enable):** A block that generates an overcurrent enable signal.
- OCSet (Overcurrent Setpoint):** A block that sets the overcurrent threshold.

11/29/2007

Pin Description

Pin	Name	Description
1	PGood	Power Good status pin. Output is open collector. Connect a pull up resistor from this pin to Vcc.
2	Vcc	This pin provides biasing voltage for the internal blocks of the IC. It also biases the low side driver. A minimum of 0.1uF, high frequency capacitor must be connected from this pin to power ground.
3	LDrv	Output driver for the low side MOSFET
4	PGnd	Power Ground. This pin serves as a separate ground for the MOSFET drivers and should be connected to the system's power ground plane.
5	HDrv	Output driver for the high side MOSFET
6	Vc	This pin powers the high side driver and must be connected to a voltage higher than bus voltage. A minimum of 0.1uF, high frequency capacitor must be connected from this pin to power ground.
7	Vsns	PGood sense pin
8	Fb	Inverting input to the error amplifier. This pin is connected directly to the output of the regulator via resistor divider to set the output voltage and provide feedback to the error amplifier.
9	Comp	Output of the error amplifier.
10	Gnd	Signal ground for internal reference and control circuitry.
11	SS/SD	Soft start / shutdown. This pin provides user programmable soft-start function. Connect an external capacitor from this pin to ground to set the start up time of the output voltage. The converter can be shutdown by pulling this pin below 0.3V.
12	OCSet	Current limit set point. A resistor from this pin to drain of the low side MOSFET will set the current limit threshold.

Recommended Operating Conditions

Symbol	Definition	Min	Max	Units
V_{CC}	Supply Voltage	4.5	14	V
V_C	Supply Voltage	Converter voltage + 5V	28	V
T_j (Note1)	Junction Temperature	-40	125	°C

Note1:

The junction temperature for 5V application is 0°C-125°C

Electrical Specifications

Unless otherwise specified, these specification apply over $V_{CC}=V_C=12V$, $0^\circ C < T_j < 105^\circ C$

Typical value are specified at $T_a=25^\circ C$

Parameter	SYM	Test Condition	Min	TYP	MAX	Units
Accuracy						
Feedback Voltage	V _{FB}			0.6		V
Accuracy		0°C<T _j <125°C	-1.5		+1.5	%
		-40°C<T _j <105°C, <i>Note2</i>	-2.5		+1.5	
Supply Current						
V _{CC} Supply Current (Static)	I _{CC(Static)}	SS=0V, No Switching		10	13	mA
V _{CC} Supply Current (Dynamic)	I _{CC(Dynamic)}	IR3629, C _{LOAD} =1.5nF		15	25	
		IR3629A, C _{LOAD} =1.5nF		15	19	
V _C Supply Current (Static)	I _{C(Static)}	SS=0V, No Switching		4.5	7	
V _C Supply Current (Dynamic)	I _{C(Dynamic)}	IR3629, C _{LOAD} =1.5nF		17	25	
		IR3629A, C _{LOAD} =1.5nF		10	15	
Under Voltage Lockout						
V _{CC} -Start-Threshold	V _{CC_} UVLO(R)	Supply ramping up	4.0	4.2	4.4	V
V _{CC} -Stop-Threshold	V _{CC_} UVLO(F)	Supply ramping down	3.7	3.9	4.1	
V _{CC} -Hysteresis	V _{CC_} Hys	Supply ramping up and down	0.15	0.25	0.3	
V _C -Start-Threshold	V _{C_} UVLO(R)	Supply ramping up	3.1	3.3	3.5	
V _C -Stop-Threshold	V _{C_} UVLO(F)	Supply ramping down	2.85	3.05	3.25	
V _C -Hysteresis	V _{C_} Hys	Supply ramping up and down	0.15	0.2	0.25	
Oscillator						
Frequency	F _S	IR3629A	270	300	330	kHz
		IR3629	540	600	660	
Ramp Amplitude	V _{ramp}	<i>Note3</i>		1.25		V
Min Duty Cycle	D _{min}	Fb=1V			0	%
Min Pulse Width	D _{min(ctrl)}	IR3629, <i>Note3</i>			80	ns
		IR3629A , <i>Note3</i>			160	
Max Duty Cycle	D _{max}	IR3629, Fb=0.5V	71			%
		IR3629A, Fb=0.5V	78			

Parameter	SYM	Test Condition	Min	TYP	MAX	Units
Error Amplifier						
Input Bias Current	I _{FB1}	SS=3V		-0.1	-0.5	μA
Input Bias Current	I _{FB2}	SS=0V	20	35	50	
Source/Sink Current	I(source/Sink)		50	70	90	
Transconductance	gm		1000	1300	1600	μmho
Soft Start/SD						
Soft Start Current	I _{SS}	SS=0V	15	20	28	μA
Shutdown Output Threshold	SD				0.25	V
Over Current Protection						
OCSET Current	I _{OCSET}		15	20	26	μA
Hiccup Current	I _{Hiccup}	Note3		3		
Hiccup Duty Cycle	Hiccup(duty)	I _{Hiccup} / I _{SS} , Note3		15		
Power Good						
Vsns Lower Trip Point	Vsns(trip)	Vsns ramping Down	0.35	0.38	0.41	V
Hysteresis	PGood(Hys)		15	27.5	40	mV
Pgood Output Low Voltage	PG(voltage)	I _{Pgood} =4mA		0.25	0.5	V
Input Bias Curent	I _{Sns}		0	0.3	1	μA
Thermal Shutdown						
Thermal Shutdown Threshold	TD	Note3		140		°C
Thermal Shutdown Hysteresis	TD(Hys)	Note3		20		
Output Drivers						
LO, Drive Rise Time	Tr(Lo)	CL=1.5nF, See Fig 3		30	60	ns
HI Drive Rise Time	Tr(Hi)	CL=1.5nF, See Fig 3		30	60	
LO Drive Fall Time	Tf(Lo)	CL=1.5nF, See Fig 3		30	60	
HI Drive Fall Time	Tf(Hi)	CL=1.5nF, See Fig 3		30	60	
Dead Band Time	Tdead	See Fig 3	10	50	100	

Note2: Cold temperature performance is guaranteed via correlation using statistical quality control. Not tested in production.

Note3: Guaranteed by Design but not tested in production.

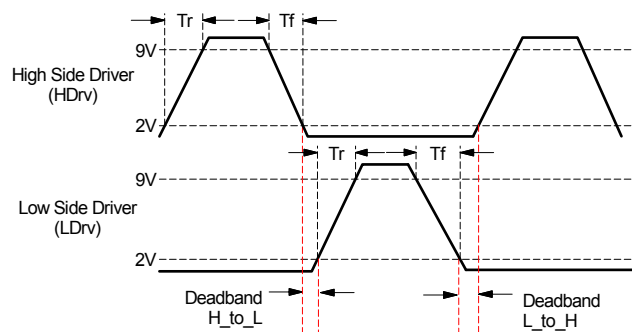
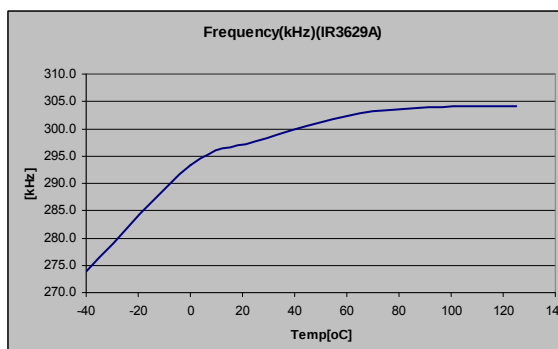
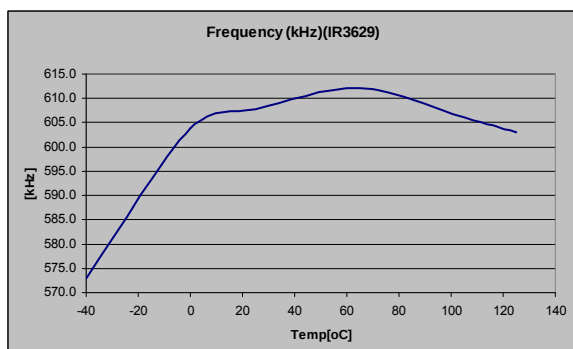
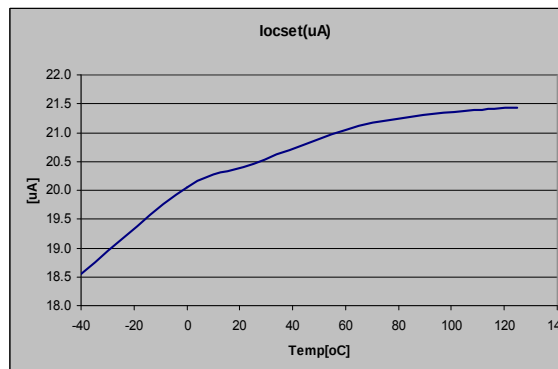
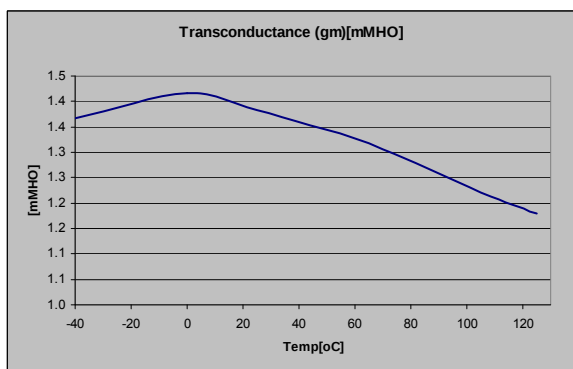
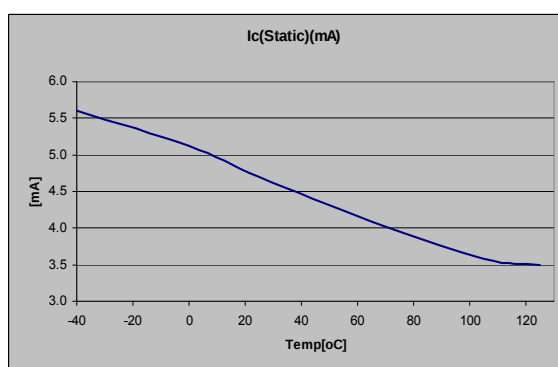
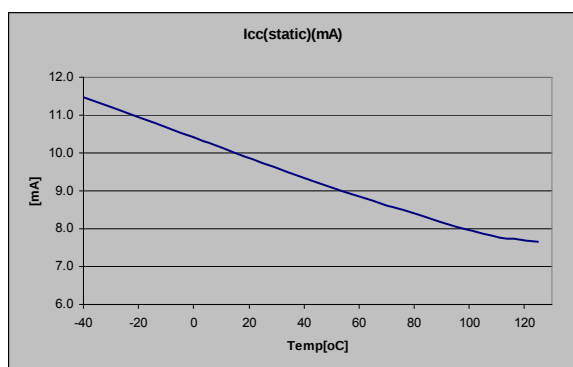
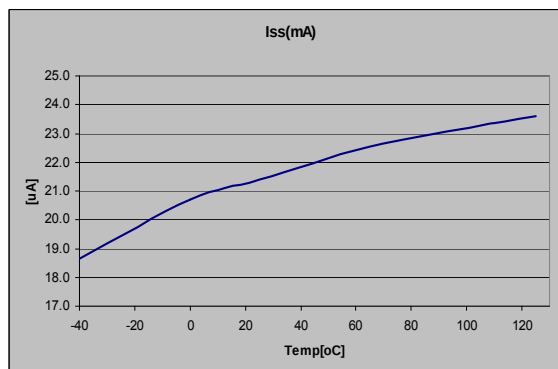
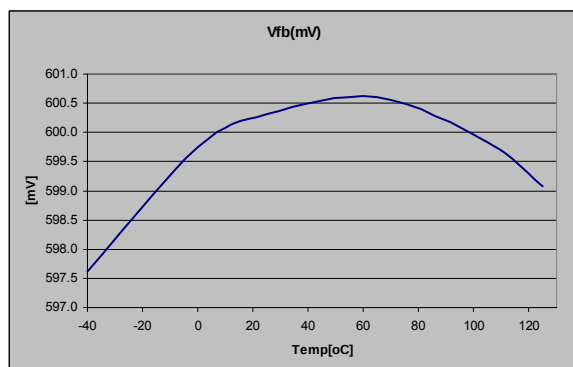


Fig. 3: Definition of Rise/Fall time and Deadband Time

TYPICAL OPERATING CHARACTERISTICS



Circuit Description

THEORY OF OPEARTION

Introduction

The IR3629/29A is a voltage mode PWM synchronous controller and operates with a fixed 600kHz (300kHz for IR3629A) switching frequency, allowing the use of small external components. The output voltage is set by a feedback pin (Fb) and the internal reference voltage (0.6V). These are the two inputs to the error amplifier. The error signal between these two inputs is amplified and it is compared to a fixed frequency linear sawtooth ramp and generates fixed frequency pulses of variable duty-cycle (D) which drives N-channel external MOSFETs.

The internal oscillator circuit uses an on-chip capacitor to set the switching frequency.

The IR3629/29A operates with single input voltage from 4.5V to 12V allowing an extended operating input voltage range.

The current limit is programmable and uses on-resistance of the low-side MOSFET, eliminating the need for an external current sense resistor.

Under-Voltage Lockout

The under-voltage lockout circuit monitors the two input supplies (Vcc and Vc) and ensures that the MOSFET driver outputs remain in the off state whenever the supply voltage drops below set thresholds. Lockout occurs if Vc or Vcc fall below 3.3V and 4.2V respectively. Normal operation resumes once Vc and Vcc rise above the set values.

Thermal Shutdown

Temperature sensing is provided inside the IR3629/29A. The trip threshold is typically set to 145°C. When the trip threshold is exceeded, thermal shutdown discharges the Soft Start voltage and turns off both MOSFETs. Thermal shutdown is not latched and automatic restart is initiated when the sensed temperature drops within the operating range. There is a 20°C hysteresis in the thermal shutdown threshold.

Power Good

The IR3629/29A provides an open collector power good signal which reports the status of the output. The output is sensed through the dedicated Vsns pin. The power good threshold can be externally programmed using two external resistors. The power good comparator is internally set to 0.38V (typical).

Shutdown

The output can be shutdown by pulling the soft-start pin below 0.3V. This can easily be done by using an external small signal transistor. During shutdown both MOSFET drivers will be turned off. Normal operation will resume by cycling the soft start pin.

Pre-Bias Startup

The IR3629/29A is able to start up into pre-charged output, which prevents oscillation and disturbances of the output voltage.

The output starts in asynchronous fashion and keeps the synchronous MOSFET off until the first gate signal for control MOSFET is generated. Figure 4 shows a typical Pre-Bias condition at startup.

Depending on the system configuration, specific amount of output capacitors may be required to prevent discharging the output voltage.

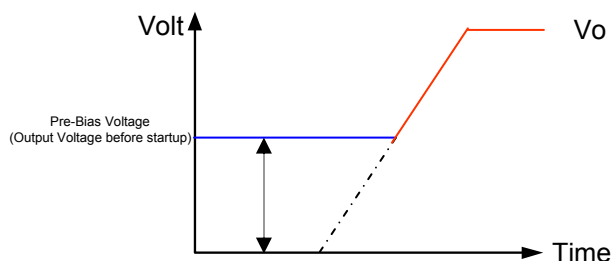


Fig. 4: Pre-Bias startup

Minimum Pulse Width

The time required for turning on and off the high side MOSFET is defined as "Minimum Pulse Width". To ensure that a reliable operation is achieved the following condition needs to be met:

$$T_{on(min)} < \frac{V_{out}}{V_{in(max)} * F_s}$$

Soft-Start

The IR3629/29A has a programmable soft-start to control the output voltage rise and limit the inrush current during start-up.

To ensure correct start-up, the soft-start sequence initiates when Vcc and Vc rise above their threshold and generate the Power On Ready (POR) signal. The soft-start function operates by sourcing current to charge an external capacitor to about 3V.

Initially, the soft-start function clamps the output of error amplifier by injecting a current (35uA) into the Fb pin and generates a voltage about 0.84V (35uA x 24K) across the negative input of error amplifier (see figure 5).

The magnitude of the injected current is inversely proportional to the voltage at the soft-start pin. As the soft-start voltage ramps up, the injected current decreases linearly and so does the voltage at the negative input of error amplifier.

When the soft-start capacitor voltage is around 1V, the voltage at the positive input of the error amplifier is approximately 0.6V.

The output of the error amplifier will start increasing and generating the first PWM signal. As the soft-start capacitor voltage continues to rise up, the current flowing into the Fb pin will keep decreasing.

The feedback voltage increases linearly as the soft-start voltage ramps up. When soft-start voltage is around 2V the output voltage reaches the steady state and the injected current is zero.

Figure 6 shows the theoretical operating waveforms during soft-start.

The output voltage start-up time is the time period when soft-start capacitor voltage increases from 1V to 2V.

The start-up time will be dependent on the size of the external soft-start capacitor and can be estimated by:

$$20\mu A * \frac{T_{start}}{C_{ss}} = 2V - 1V$$

For a given start-up time, the soft-start capacitor (nF) can be estimated as:

$$C_{ss} \cong 20\mu A * T_{start}(ms) \quad --(1)$$

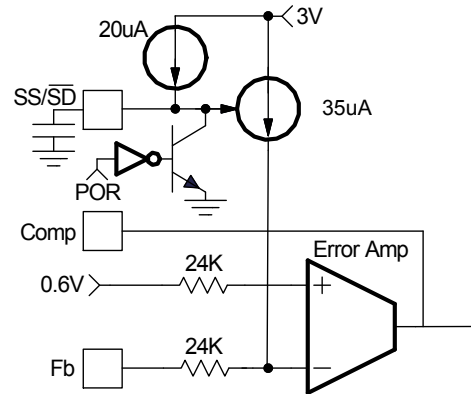


Fig. 5: Soft-Start circuit for IR3629/29A

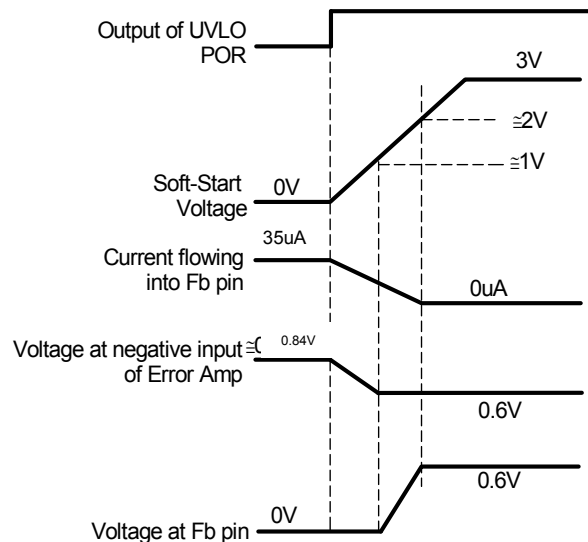


Fig. 6: Theoretical operation waveforms during soft-start

Over-Current Protection

The over current protection is performed by sensing current through the $R_{DS(on)}$ of the low-side MOSFET. This method enhances the converter's efficiency and reduces cost by eliminating a current sense resistor. As shown in figure 7, an external resistor (R_{SET}) is connected between OCSet pin and the drain of the low-side MOSFET (Q2) which determines the current limit set point.

The internal current source develops a voltage across R_{SET} . When the low-side MOSFET is turned on, the inductor current flows through the Q2 and results in a voltage which is given by:

$$V_{OCSet} = (I_{OCSet} * R_{OCSet}) - (R_{DS(on)} * I_L) \quad --(2)$$

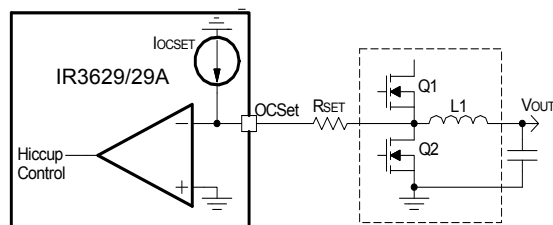


Fig. 7: Connection of over current sensing resistor

The critical inductor current can be calculated by setting:

$$V_{OCSet} = (I_{OCSet} * R_{OCSet}) - (R_{DS(on)} * I_L) = 0$$

$$I_{SET} = I_{L(critical)} = \frac{R_{OCSet} * I_{OCSet}}{R_{DS(on)}} \quad --(3)$$

An over-current is detected if the OCSet pin goes below ground. This trips the OCP comparator and cycles the soft start function in hiccup mode.

The hiccup is performed by charging and discharging the soft-start capacitor in a certain slope rate. As shown in figure 8, a 3uA current source is used to discharge the soft-start capacitor.

The OCP comparator resets after every soft start cycle. The converter stays in this mode until the overload or short circuit is removed. The converter will automatically recover.

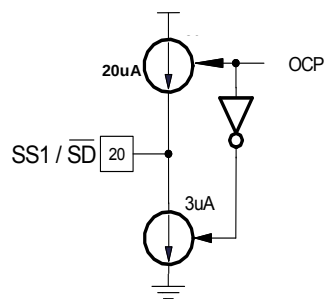


Fig. 8: 3uA current source for discharging soft-start capacitor during hiccup

The OCP circuit starts sampling current when the low gate drive is about 3V. The OCSet pin is internally clamped during deadtime to prevent false triggering. Figure 9 shows the OCSet pin during one switching cycle. As shown, there is about 150ns delay to mask the deadtime. Since this node contains switching noises, this delay also functions as a filter.

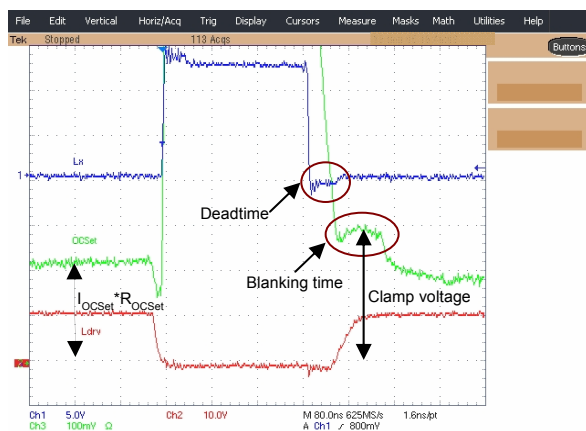


Fig. 9: OCset pin during normal condition
Ch1: Inductor point, Ch2:Ldrv, Ch3:OCSet

The value of R_{SET} should be checked in an actual circuit to ensure that the over-current protection circuit activates as expected. The IR3629 current limit is designed primarily as a disaster preventing, "no blow up" circuit, and does not operate as a precision current regulator.

Application Information

Design Example:

The following example is a typical application for IR3629A. The application circuit is shown on page 18.

$$V_{in}=12V, (13.2V, \max)$$

$$V_o=1.8V$$

$$I_o=25A$$

$$\Delta V_o \leq 54mV (\text{output voltage ripple})$$

$$F_s=300kHz$$

Output Voltage Programming

Output voltage is programmed by reference voltage and external voltage divider. The Fb pin is the inverting input of the error amplifier, which is internally referenced to 0.6V. The divider is ratioed to provide 0.6V at the Fb pin when the output is at its desired value. The output voltage is defined by using the following equation:

$$V_o = V_{ref} * \left(1 + \frac{R_8}{R_9}\right) \quad --(4)$$

When an external resistor divider is connected to the output as shown in figure 10.

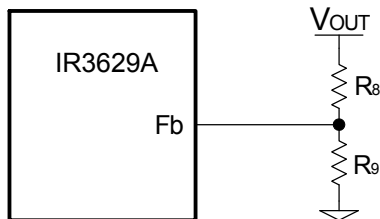


Fig. 10: Typical application of the IR3629A for programming the output voltage

Equation (4) can be rewritten as:

$$R_9 = R_8 * \left(\frac{V_{ref}}{V_o - V_{ref}}\right) \quad --(5)$$

For the calculated values of R_8 and R_9 see feedback compensation section.

Soft-Start Programming

The soft-start timing can be programmed by selecting the soft-start capacitance value. The start-up time of the converter can be calculated by using:

$$C_{SS} \cong 20\mu A * T_{start} \quad --(1)$$

Where T_{start} is the desired start-up time (ms).

For a start-up time of 10ms, the soft-start capacitor will be 0.2uF. Choose a ceramic capacitor at 0.22uF.

Vc supply for single input voltage

To drive the high side switch, it is necessary to supply a gate voltage at least 4V greater than the bus voltage. This is achieved by using a charge pump configuration as shown in figure 11. This method is simple and inexpensive. The operation of the circuit is as follows: when the lower MOSFET is turned on, the capacitor (C1) is pulled down to ground and charges, up to V_{BUS} value, through the diode (D1). The bus voltage will be added to this voltage when the upper MOSFET turns on in the next cycle, and providing supply voltage (Vc) through diode (D2). Vc is approximately:

$$V_c \cong 2 * V_{bus} - (V_{D1} + V_{D2}) \quad --(6)$$

A capacitors in the range of 0.1uF is generally adequate for most applications. Fast recovery diodes must be used to minimize the amount of charge fed back from the charge pump capacitor into V_{BUS} . The diodes need to be able to block the full power rail voltage, which is seen when the high-side MOSFET is switched on. For low-voltage applications, schottky diodes can be used to minimize forward drop.

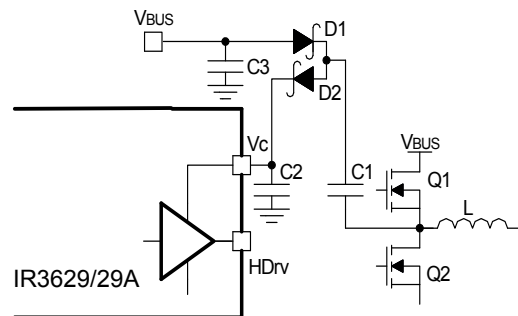


Fig. 11: Charge pump circuit to generate Vc voltage

Input Capacitor Selection

The ripple current generated during the on time of upper the MOSFET should be provided by the input capacitor. The RMS value of this ripple is expressed by:

$$I_{RMS} = I_o * \sqrt{D * (1-D)} \quad --(7)$$

Where: $D = \frac{V_o}{V_{in}}$

D is the Duty Cycle

I_{RMS} is the RMS value of the input capacitor current.

I_o is the output current.

For $I_o=25A$ and $D=0.15$, the $I_{RMS}=8.9A$.

Ceramic capacitors are recommended due to their peak current capabilities, they also feature low ESR and ESL at higher frequency which enables better efficiency. However, for the large pulsing input current at full load, 2x270uF 16V OS-CON capacitors from Sanyo are recommended, as well as 2x10uF 16V ceramic capacitors from Murata.

Inductor Selection

The inductor is selected based on output power, operating frequency and efficiency requirements. A low inductor value causes large ripple current, resulting in the smaller size, faster response to a load transient but poor efficiency and high output noise. Generally, the selection of the inductor value can be reduced to the desired maximum ripple current in the inductor (ΔI). The optimum point is usually found between 20% and 50% ripple of the output current.

For the buck converter, the inductor value for the desired operating ripple current can be determined using the following relation:

$$V_{in} - V_o = L * \frac{\Delta I}{\Delta t}; \quad \Delta t = D * \frac{1}{F_s}$$

$$L = (V_{in} - V_o) * \frac{V_o}{V_{in} * \Delta I * F_s} \quad --(8)$$

Where:

V_{in} = Maximum input voltage

V_o = Output Voltage

ΔI = Inductor ripple current

F_s = Switching frequency

Δt = Turn on time

D = Duty cycle

If $\Delta I \approx 40\%(I_o)$, then the output inductor will be:

$$L \approx 0.6\mu H$$

The MPL104-0R6 from Delta provides a compact, low profile inductor suitable for this application.

Output Capacitor Selection

The voltage ripple and transient requirements determine the output capacitors type and values. The criteria is normally based on the value of the Effective Series Resistance (ESR). However the actual capacitance value and the Equivalent Series Inductance (ESL) are other contributing components. These components can be described as:

$$\Delta V_o = \Delta V_{o(ESR)} + \Delta V_{o(ESL)} + \Delta V_{o(C)}$$

$$\Delta V_{o(ESR)} = \Delta I_L * ESR \quad --(9)$$

$$\Delta V_{o(ESL)} = \left(\frac{V_{in}}{L} \right) * ESL$$

$$\Delta V_{o(C)} = \frac{\Delta I_L}{8 * C_o * F_s}$$

$$\Delta V_o = \text{Output voltage ripple}$$

$$\Delta I_L = \text{Inductor ripple current}$$

Since the output capacitor has a major role in the overall performance of the converter and determines the result of transient response, selection of the capacitor is critical. The IR3629A can perform well with all types of capacitor.

As a rule, the capacitor must have low enough ESR to meet output ripple and load transient requirements.

The goal for this design is to meet the voltage ripple requirement in the smallest possible capacitor size. Therefore a SP capacitor is selected due to large capacitance and small size. Two of the Panasonic SP-CAP EEFSX0D331XE (330uF, 2V, 6mOhm) is a good choice. In this case, the ESR dominates the output voltage ripple, equation (9) can be used to calculate the required ESR for the specific voltage ripple.

Power MOSFET Selection

The IR3629A uses two N-Channel MOSFETs per channel. The selection criteria to meet power transfer requirements are based on maximum drain-source voltage (V_{DS}), gate-source drive voltage (V_{GS}), maximum output current, On-resistance $R_{DS(on)}$, and thermal management.

The MOSFET must have a maximum operating voltage (V_{DS}) exceeding the maximum input voltage (V_{in}).

The gate drive requirement is almost the same for both MOSFETs. A logic-level transistor can be used and caution should be taken with devices at very low gate threshold voltage (V_{GS}) to prevent undesired turn-on of the complementary MOSFET, which results in a shoot-through current.

The total power dissipation for MOSFETs includes conduction and switching losses. For the Buck converter the average inductor current is equal to the DC load current. The conduction loss is defined as:

$$P_{cond} = (I_{load}^2 * R_{ds(on)} * D * \theta)$$

$$P_{cond} = (I_{load}^2 * R_{ds(on)} * (1-D) * \theta)$$

$$\theta = R_{ds(on)} \text{ temperature dependency}$$

The $R_{DS(on)}$ temperature dependency should be considered for the worst case operation. This is typically given in the MOSFET datasheet. Ensure that the conduction losses and switching losses do not exceed the package ratings or violate the overall thermal budget.

For this design, the IRF6712 is selected for control FET and IRF6715 is selected for the synchronous FET. These devices provide low on resistance in a DirectFET package.

The MOSFETs have the following data:

ControlFET(IRF6712)	SyncFET(IRF6715)
$V_{ds} = 25V, Q_g = 12nC$	$V_{ds} = 25V, Q_g = 40nC$
$R_{ds(on)} = 3.8m\Omega @ V_{gs} = 10V$	$R_{ds(on)} = 1.3m\Omega @ V_{gs} = 10V$

The conduction losses will be: $P_{con} = 1.05W$ at $I_o = 25A$. The switching loss is more difficult to calculate, even though the switching transition is well understood. The reason is the effect of the parasitic components and switching times during the switching procedures such as turn-on / turn-off delays and rise and fall times. The control MOSFET contributes to the majority of the

switching losses in a synchronous Buck converter. The synchronous MOSFET turns on under zero voltage conditions, therefore, the turn on losses for synchronous MOSFET can be neglected. With a linear approximation, the total switching loss can be expressed as:

$$P_{sw} = \frac{V_{ds(off)}}{2} * \frac{t_r + t_f}{T} * I_{load} \quad \text{--- (10)}$$

Where:

$V_{ds(off)}$ = Drain to source voltage at the off time

t_r = Rise time

t_f = Fall time

T = Switching period

I_{load} = Load current

The switching time waveforms is shown in figure12.

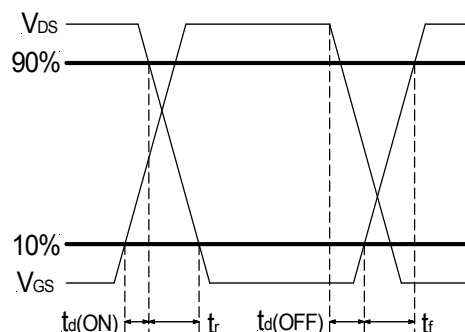


Fig. 12: switching time waveforms

From IRF6712 data sheet:

$t_r = 11ns$

$t_f = 19ns$

These values are taken under a certain test condition. For more details please refer to the IRF6712 data sheet.

By using equation (10), we can calculate the switching losses. $P_{sw} = 1.35W$ at $I_o = 25A$.

The reverse recovery loss is also another contributing factor in control FET switching losses. This is equivalent to extra current required to remove the minority charges from the synchronous FET. The reverse recovery loss can be expressed as:

$$P_{Qrr} = Q_{rr} * t_{rr} * F_s$$

Q_{rr} : Reverse Recovery Charge
 t_{rr} : Reverse Recovery Time
 F_s : Switching Frequency

Feedback Compensation

The IR3629A is a voltage mode controller. The control loop is a single voltage feedback path including error amplifier and error comparator. To achieve fast transient response and accurate output regulation, a compensation circuit is necessary. The goal of the compensation network is to provide a closed-loop transfer function with the highest 0dB crossing frequency and adequate phase margin (greater than 45°).

The output LC filter introduces a double pole, –40dB/decade gain slope above its corner resonant frequency, and a total phase lag of 180° (see figure 13). The resonant frequency of the LC filter is expressed as follows:

$$F_{LC} = \frac{1}{2 * \pi * \sqrt{L_o * C_o}} \quad \text{--- (11)}$$

Figure 13 shows gain and phase of the LC filter. Since we already have 180° phase shift from the output filter alone, the system risks being unstable.

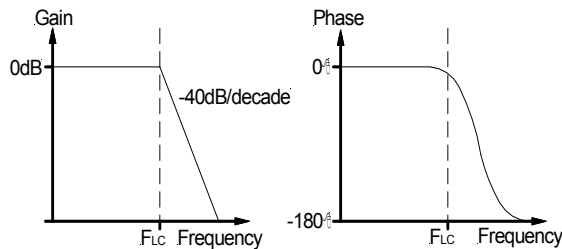


Fig. 13: Gain and Phase of LC filter

The IR3629/29A's error amplifier is a differential-input transconductance amplifier. The output is available for DC gain control or AC phase compensation.

The error amplifier can be compensated either in type II or type III compensation. When it is used in type II compensation the transconductance properties of the error amplifier become evident and can be used to cancel one of the output filter poles. This will be accomplished with a series RC circuit from Comp pin to ground as shown in figure 14.

This method requires the output capacitor should have enough ESR to satisfy stability requirements. In general the output capacitor's ESR generates a zero typically at 5kHz to 50kHz which is essential for an acceptable phase margin.

The ESR zero of the output capacitor expressed as follows:

$$F_{ESR} = \frac{1}{2 * \pi * ESR * C_o} \quad \text{--- (12)}$$

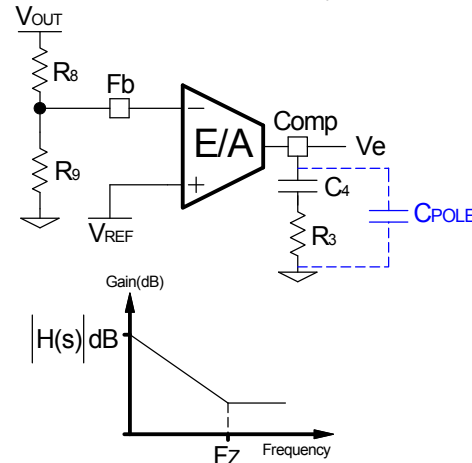


Fig. 14: Typell compensation network and its asymptotic gain plot

The transfer function (Ve/Vo) is given by:

$$H(s) = \left(g_m * \frac{R_9}{R_9 + R_8} \right) * \frac{1 + sR_3C_4}{sC_4} \quad \text{--- (13)}$$

The (s) indicates that the transfer function varies as a function of frequency. This configuration introduces a gain and zero, expressed by:

$$[H(s)] = \left(g_m * \frac{R_9}{R_9 + R_8} \right) * R_3 \quad \text{--- (14)}$$

$$F_z = \frac{1}{2\pi * R_3 * C_4} \quad \text{--- (15)}$$

The gain is determined by the voltage divider and error amplifier's transconductance gain. First select the desired zero-crossover frequency (Fo):

$$F_o > F_{ESR} \text{ and } F_o \leq (1/5 \sim 1/10) * F_s$$

Use the following equation to calculate R3:

$$R_3 = \frac{V_{osc} * F_o * F_{ESR} * (R_8 + R_9) * 1.28}{V_{in} * F_{LC}^2 * R_9 * g_m} \quad \text{--- (15A)}$$

Where:

V_{in} = Maximum Input Voltage

V_{osc} = Oscillator Ramp Voltage

F_o = Crossover Frequency

F_{ESR} = Zero Frequency of the Output Capacitor

F_{LC} = Resonant Frequency of the Output Filter

R_8 and R_9 = Feedback Resistor Dividers

g_m = Error Amplifier Transconductance

1.28 = Empirical number to compensate thermal, process variations and components tolerances

To cancel one of the LC filter poles, place the zero before the LC filter resonant frequency pole:

$$F_z = 75\%F_{LC}$$

$$F_z = 0.75 * \frac{1}{2\pi\sqrt{L_o * C_o}} \quad \text{--- (16)}$$

Using equations (15) and (16) to calculate C9. One more capacitor is sometimes added in parallel with C4 and R3. This introduces one more pole which is mainly used to suppress the switching noise.

The additional pole is given by:

$$F_p = \frac{1}{2\pi * R_3 * \frac{C_4 * C_{POLE}}{C_4 + C_{POLE}}}$$

The pole sets to one half of the switching frequency which results in the capacitor C_{POLE}:

$$C_{POLE} = \frac{1}{\pi * R_3 * F_s - \frac{1}{C_4}} \cong \frac{1}{\pi * R_3 * F_s}$$

For a general solution for unconditional stability for any type of output capacitors, in a wide range of ESR values we should implement local feedback with a compensation network (type III). The typically used compensation network for voltage-mode controller is shown in figure 15.

In such configuration, the transfer function is given by:

$$\frac{V_e}{V_o} = \frac{1 - g_m Z_f}{1 + g_m Z_{in}}$$

The error amplifier gain is independent of the transconductance under the following condition:

$$g_m * Z_f \gg 1 \text{ and } g_m * Z_{in} \gg 1 \quad \text{--- (17)}$$

By replacing Z_{in} and Z_f according to figure 15, the transfer function can be expressed as:

$$H(s) = \frac{1}{sR_8(C_4 + C_3)} * \frac{(1 + sR_3C_4) * [1 + sC_7(R_8 + R_{10})]}{\left[1 + sR_3\left(\frac{C_4 * C_3}{C_4 + C_3}\right)\right] * (1 + sR_{10}C_7)}$$

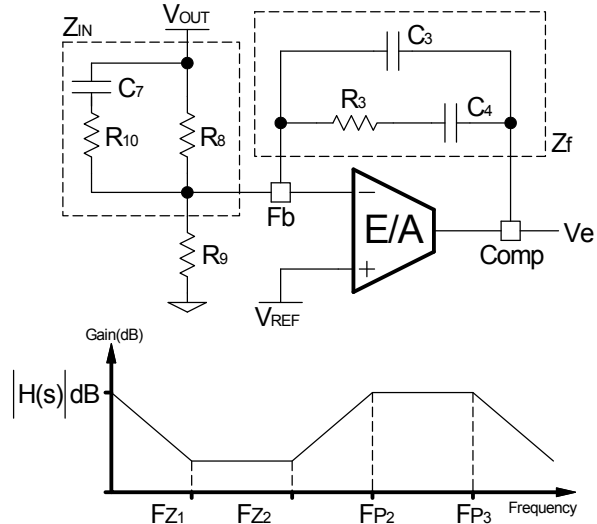


Fig.15: Compensation network with local feedback and its asymptotic gain plot

As known, the transconductance amplifier has a high impedance (current source) output, therefore, consideration should be taken when loading the error amplifier output. It may exceed its source/sink output current capability, so that the amplifier will not be able to swing its output voltage over the necessary range.

The compensation network has three poles and two zeros and they are expressed as follows:

$$F_{P1} = 0$$

$$F_{P2} = \frac{1}{2\pi * R_{10} * C_7}$$

$$F_{P3} = \frac{1}{2\pi * R_3 * \left(\frac{C_4 * C_3}{C_4 + C_3}\right)} \cong \frac{1}{2\pi * R_3 * C_3}$$

$$F_{Z1} = \frac{1}{2\pi * R_3 * C_4}$$

$$F_{Z2} = \frac{1}{2\pi * C_7 * (R_8 + R_{10})} \cong \frac{1}{2\pi * C_7 * R_8}$$

Cross over frequency is expressed as:

$$F_o = R_3 * C_7 * \frac{V_{in} * 1}{V_{osc} * 2\pi * L_o * C_o}$$

Based on the frequency of the zero generated by the output capacitor and its ESR versus crossover frequency, the compensation type can be different. The table below shows the compensation types and location of the crossover frequency.

Compensator type	F_{ESR} vs. F_o	Output capacitor
Type II(PI)	$F_{LC} < F_{ESR} < F_o < F_{s/2}$	Electrolytic, Tantalum
Type III(PID) Method A	$F_{LC} < F_o < F_{ESR} < F_{s/2}$	Tantalum, ceramic
Type III(PID) Method B	$F_{LC} < F_o < F_{s/2} < F_{ESR}$	Ceramic

Table1- The compensation type and location of F_{ESR} versus F_o

The details of these compensation types are discussed in application note AN-1043 which can be downloaded from IR's website at www.irf.com.

For this design we have:

$$\begin{aligned}
 V_{in} &= 12V \\
 V_o &= 1.8V \\
 V_{osc} &= 1.25V \\
 V_{ref} &= 0.6V \\
 g_m &= 1000\mu m \\
 L_o &= 0.6\mu H \\
 C_o &= 2 \times 330\mu F, ESR = 6m\Omega/\text{each}
 \end{aligned}$$

These result to:

$$\begin{aligned}
 F_{LC} &= 8kHz \\
 F_{ESR} &= 80.38kHz \\
 F_{s/2} &= 150kHz
 \end{aligned}$$

Select crossover frequency:

$$F_o < F_{ESR} \text{ and } F_o \leq (1/5 \sim 1/10) * F_s$$

$$F_o = 60kHz$$

Since: $F_{LC} < F_o < F_{ESR} < F_{s/2}$, Type III Method A is selected to place the pole and zeros.

The following design rules will give a crossover frequency approximately one-fifth of the switching frequency. The higher the band width, the potentially faster the load transient response. The DC gain will be large enough to provide high DC-regulation accuracy (typically -5dB to -12dB). The phase margin should be greater than 45° for overall stability.

Detailed calculation of compensation Type III Method A:

$$F_{Z2} = F_{LC} = 8kHz$$

$$F_{P2} = F_{ESR} = 80.38kHz$$

$$\text{Select: } F_{Z1} = 0.75 * F_{Z2} = 6kHz \text{ and } F_{P3} = 0.5 * F_s = 150kHz$$

$$R_3 \geq \frac{2}{g_m}; R_3 \geq 2K\Omega; \text{ Select: } R_3 = 26.7K\Omega$$

Calculate C_4 , C_3 and C_7 :

$$C_4 = \frac{1}{2\pi * F_{Z1} * R_3}; C_4 = 0.99nF, \text{ Select: } C_4 = 1nF$$

$$C_3 = \frac{1}{2\pi * F_{P3} * R_3}; C_3 = 39.74pF, \text{ Select: } C_3 = 39pF$$

$$C_7 = \frac{2\pi * F_o * L_o * C_o * V_{osc} * 1.28}{R_3 * V_{in}}; C_7 = 0.58nF,$$

$$\text{Select: } C_7 = 0.56nF$$

Calculate R_{10} , R_8 and R_9 :

$$R_{10} = \frac{1}{2\pi * C_7 * F_{P2}}; R_{10} = 3.54K\Omega, \text{ Select: } R_{10} = 3.57K\Omega$$

$$R_8 = \frac{1}{2\pi * C_7 * F_{Z2}} * R_{10}; R_8 = 31.97K\Omega, \text{ Select: } R_8 = 31.60K\Omega$$

$$R_9 = \frac{V_{ref}}{V_o} * R_8; R_9 = 15.8K\Omega, \text{ Select: } R_9 = 15.8K\Omega$$

Programming the Current-Limit

The Current-Limit threshold can be set by connecting a resistor (R_{SET}) from the drain of the low-side MOSFET to the OCSet pin. The resistor can be calculated by using equation (3). The $R_{DS(on)}$ has a positive temperature coefficient and it should be considered for the worst case operation. This resistor must be placed close to the IC, place a small ceramic capacitor from this pin to ground for noise rejection purposes.

$$I_{SET} = I_{L(critical)} = \frac{R_{OCSet} * I_{OCSet}}{R_{DS(on)}} \quad --(3)$$

$$R_{DS(on)} = 1.3m\Omega * 1.5 = 1.95m\Omega$$

$$I_{SET} \cong I_{o(LIM)} = 25.4 * 1.5 = 37.5A$$

(50% over nominal output current)

$$R_{OCSet} = 3.65K\Omega \quad \text{Select } R_7 = 3.65K\Omega$$

Setting the Power Good Threshold

Power Good threshold can be programmed by using two external resistors (R_1 , R_2 in figure 16).

The following formulas can be used to set the threshold:

$$R_2 = \frac{0.38V}{0.9 * V_{out} - 0.38V} * R_1 \quad --(18)$$

Where;

0.38V is reference of the internal comparator

0.9* V_{out} is selectable threshold for power good, for this design it is 1.62V.

Select $R_1 = 10K\Omega$

Using (18): $R_2 = 3.06K\Omega$

Select $R_2 = 3.09K$

Use a pull up resistor (4.99K) from PGood pin to V_{cc} .

Layout Consideration

The layout is very important when designing high frequency switching converters. Poor layout will affect noise pickup and can cause a good design to perform with less than expected results.

Start to place the power components, making all the connection in the top layer with wide, copper filled areas. The inductor, output capacitors and the MOSFETS should be as close to each other as possible. This helps to reduce the EMI radiated by the power traces due to the high switching currents through them. Place input capacitor very close to the drain of the high-side MOSFET, to reduce the ESR replace the single input capacitor with two parallel units.

The feedback part of the system should be kept away from the inductor and other noise sources.

The critical bypass components such as capacitors for V_{cc} and V_c should be close to the respective pins. It is important to place the feedback components including feedback resistors and compensation components close to Fb and Comp pins.

In a multilayer PCB use one layer as a power ground plane and have a control circuit ground (analog ground), to which all signals are referenced. The goal is to localize the high current path to a separate loop that does not interfere with the more sensitive analog control function. These two grounds must be connected together on the PC board layout at a single point.

The MLPD is a thermally enhanced package. Based on thermal performance it is recommended to use 4-layers PCB. To effectively remove heat from the device the exposed pad should be connected to ground plane using vias.

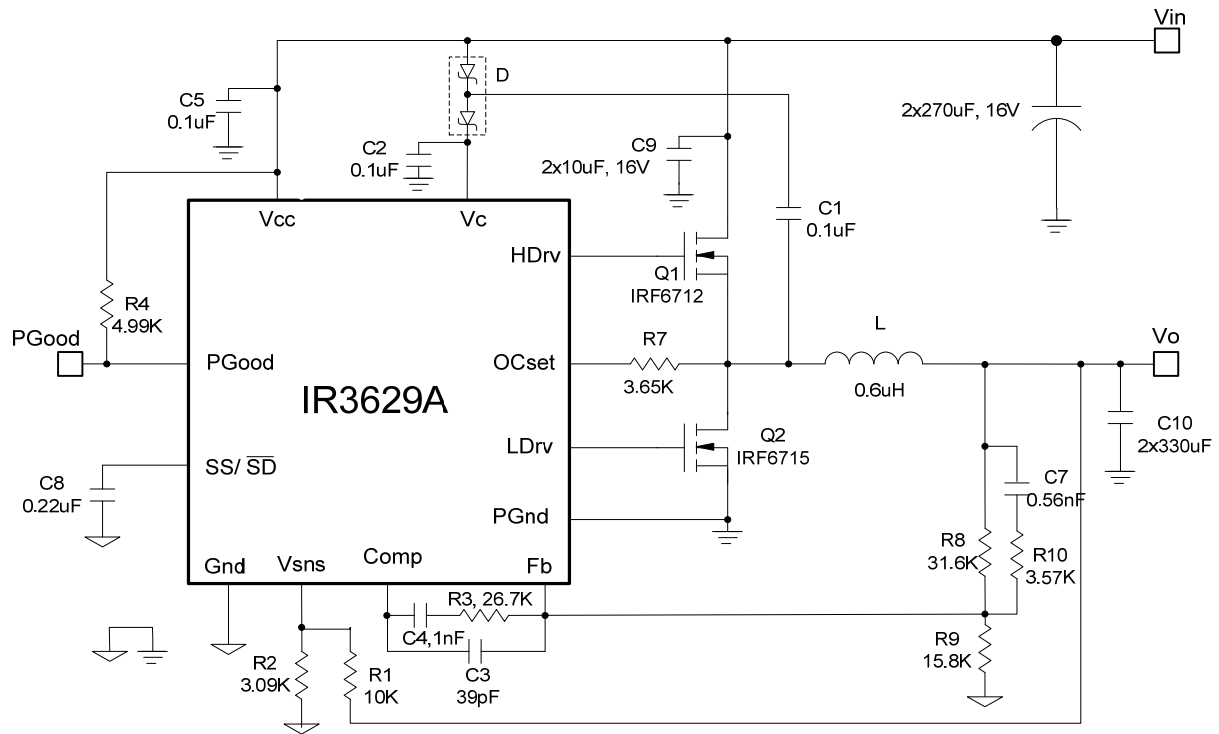
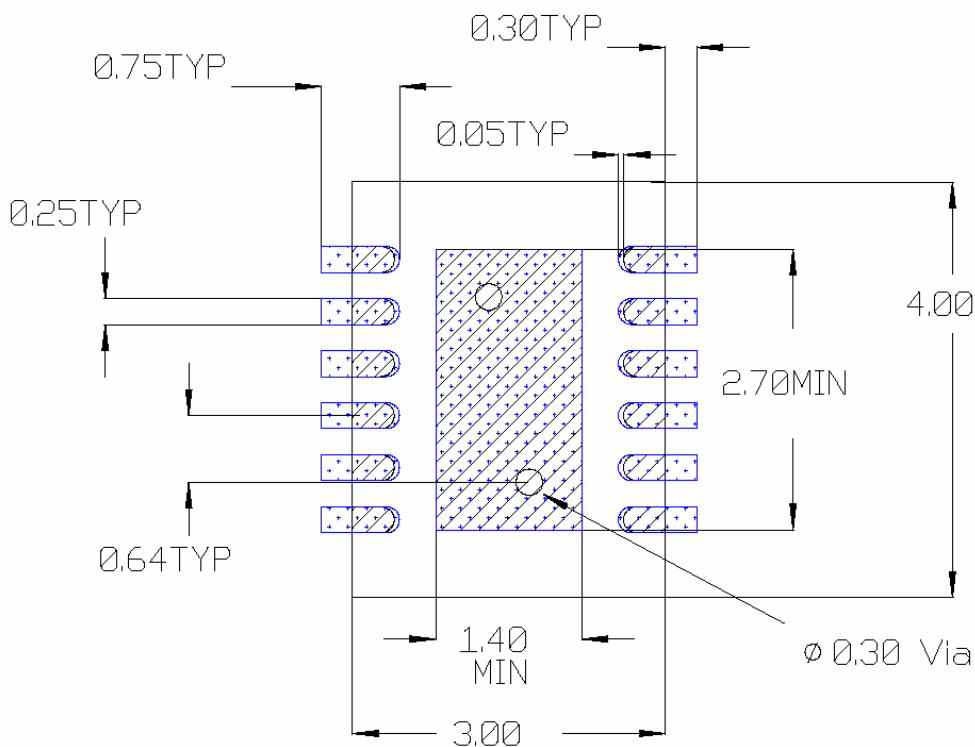


Fig.16: Application circuit for IR3629A 12Vin to 1.8Vout

PCB Metal and Components Placement

- The lead land width should be equal to the nominal part lead width. The minimum lead to lead spacing should be $\geq 0.2\text{mm}$ to minimize shorting.
- The lead land length should be equal to maximum part lead length + 0.3 mm outboard extension + 0.05mm inboard extension. The outboard extension ensures a large and inspectable toe fillet, and the inboard extension will accommodate any part misalignment and ensure a fillet.
- The center pad land length and width should be equal to maximum part pad length and width. However, the minimum metal to metal spacing should be $\geq 0.17\text{mm}$ for 2 oz. Copper ($\geq 0.1\text{mm}$ for 1 oz. Copper and $\geq 0.23\text{mm}$ for 3 oz. Copper).
- Two 0.30mm diameter via should be placed in the center of the pad land and connected to ground to minimize the noise effect on the IC.



All Dimensions in mm



Solder Resist

- The solder resist should be pulled away from the metal lead lands by a minimum of 0.06mm. The solder resist mis-alignment is a maximum of 0.05mm and it is recommended that the lead lands are all Non Solder Mask Defined (NSMD). Therefore pulling the S/R 0.06mm will always ensure NSMD pads.

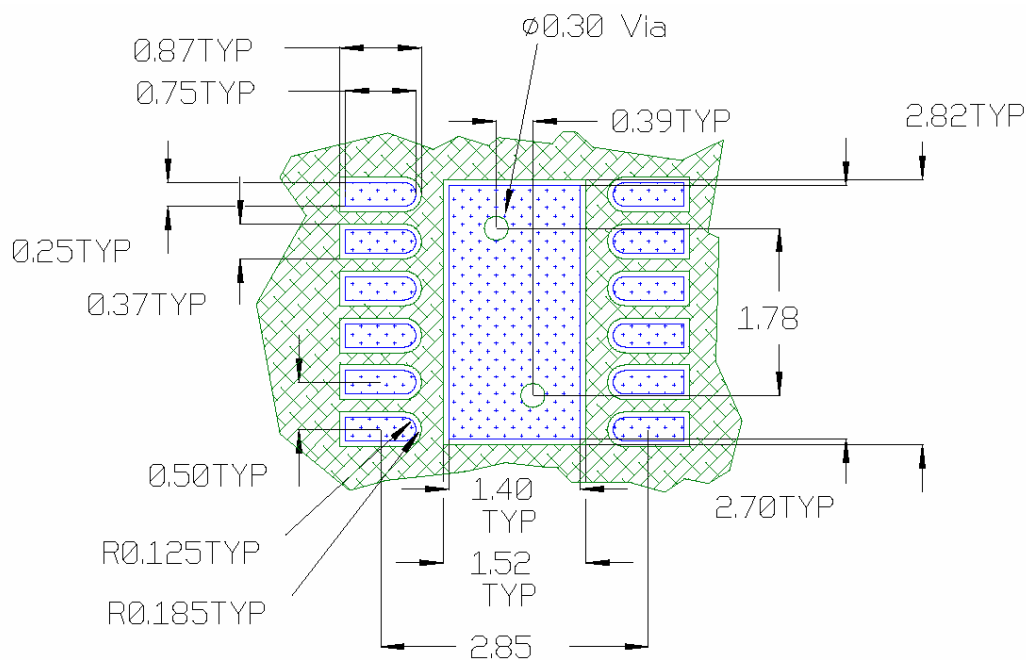
- The minimum solder resist width is 0.13mm.

At the inside corner of the solder resist where the lead land groups meet, it is recommended to provide a fillet so a solder resist width of $\geq 0.17\text{mm}$ remains.

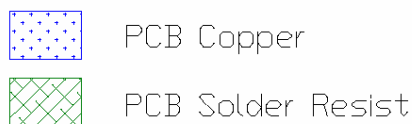
- The land pad should be Non Solder Mask Defined (NSMD), with a minimum pullback of the solder resist off the copper of 0.06mm to accommodate solder resist mis-alignment.

- Ensure that the solder resist in-between the lead lands and the pad land is $\geq 0.15\text{mm}$ due to the high aspect ratio of the solder resist strip separating the lead lands from the pad land.

- Each via in the land pad should be tented or plugged from bottom boardside with solder resist.

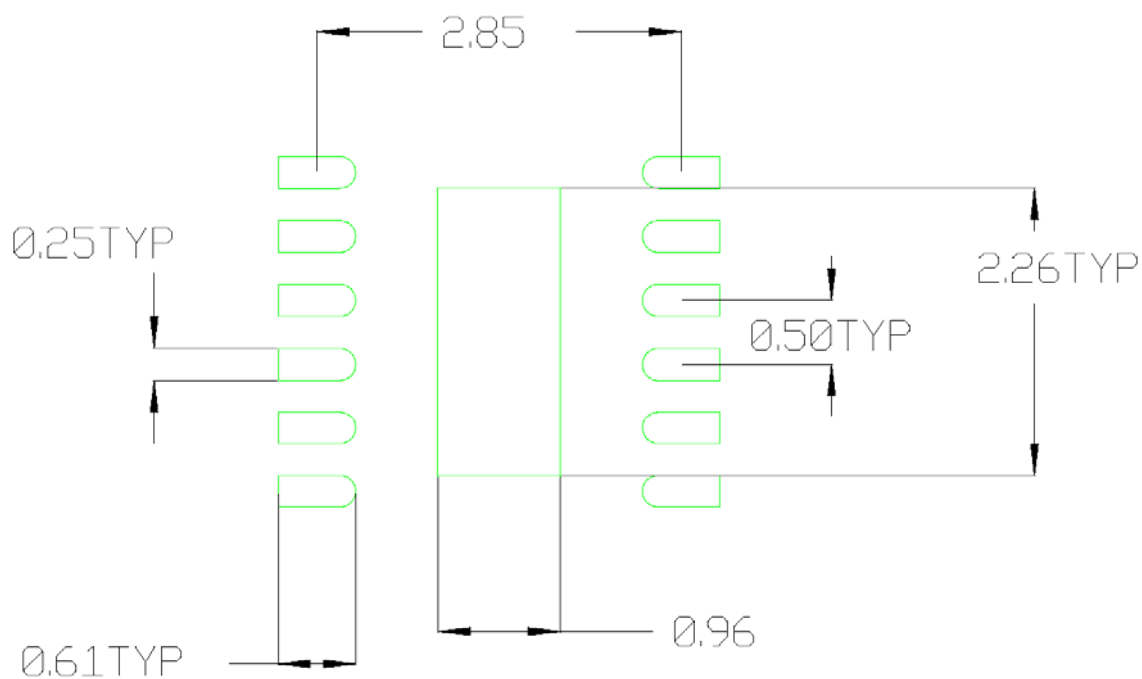


All Dimensions in mm



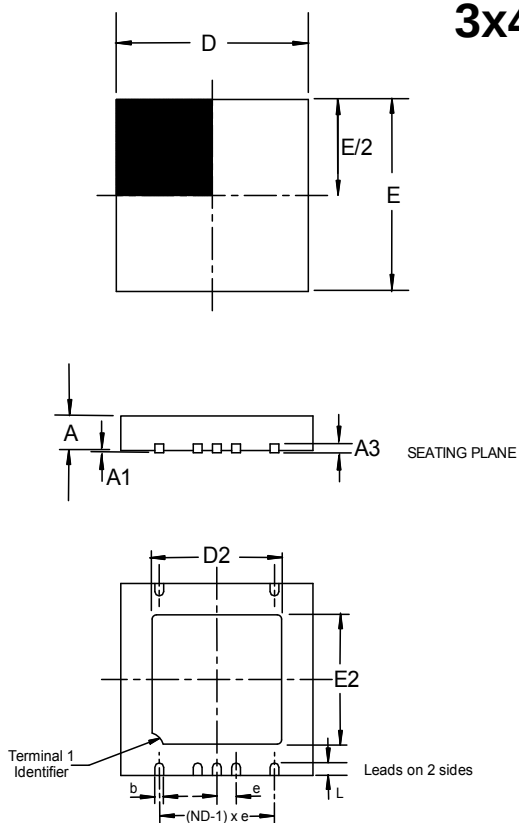
Stencil Design

- The stencil apertures for the lead lands should be approximately 80% of the area of the lead lands. Reducing the amount of solder deposited will minimize the occurrence of lead shorts. Since for 0.5mm pitch devices the leads are only 0.25mm wide, the stencil apertures should not be made narrower; openings in stencils < 0.25mm wide are difficult to maintain repeatable solder release.
- The stencil lead land apertures should therefore be shortened in length by 80% and centered on the lead land.
- The land pad aperture should deposit approximately 50% area of solder on the center pad. If too much solder is deposited on the center pad the part will float and the lead lands will be open.
- The maximum length and width of the land pad stencil aperture should be equal to the solder resist opening minus an annular 0.2mm pull back to decrease the incidence of shorting the center land to the lead lands when the part is pushed into the solder paste.



Stencil Aperture
All Dimensions in mm

(IR3629/IR3629A M) MLPD Package
3x4-12Lead



SYMBOL	VGED-4					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	.032	.035	.039
A1	0.00	0.02	0.05	.000	.0008	.0019
A3	0.20 REF			.008 REF		
b	0.18	0.25	0.30	.0071	.0096	.0118
D2	3.0	—	3.70	.118	—	.145
D	4.00 BSC			.157 BSC		
E	3.00 BSC			.118 BSC		
E2	1.40	—	1.80	.055	—	.070
L	0.30	0.40	0.50	.012	.016	.019
e	0.50 PITCH			.020 PITCH		
N	12			10		
ND	6			6		

TAPE & REEL ORIENTATION

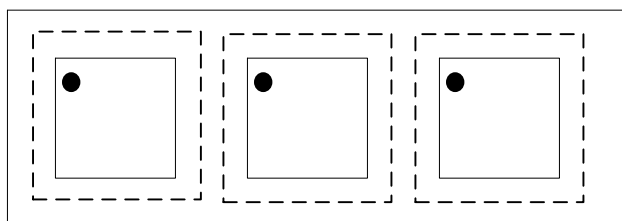
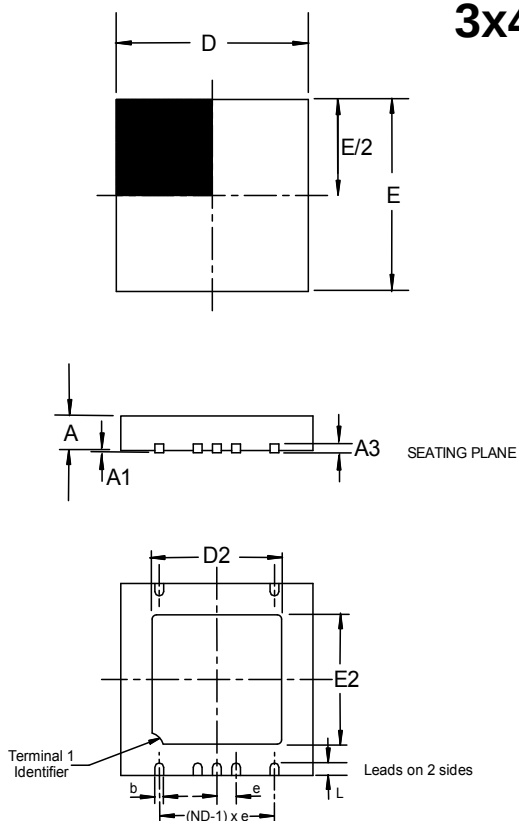


Figure A

(IR3629M) MLPD Package 3x4-12Lead



S Y M B O L	VEED-5					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	.032	.035	.039
A1	0.00	0.02	0.05	.000	.0008	.0019
A3	0.20 REF			.008 REF		
b	0.18	0.25	0.30	.0071	.0098	.0118
D2	2.20	—	2.70	.087	—	.106
D	3.00 BSC			.118 BSC		
E	3.00 BSC			.118 BSC		
E2	1.40	—	1.75	.055	—	.068
L	0.30	0.40	0.50	.012	.016	.019
e	0.50 PITCH			.020 PITCH		
N	10			10		
ND	5			5		

TAPE & REEL ORIENTATION

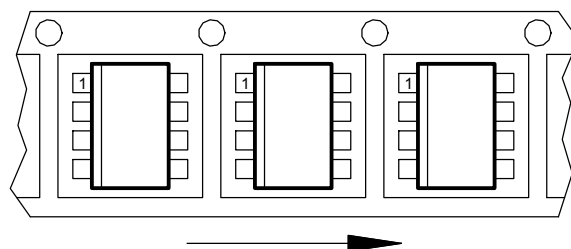


Figure A

Mouser Electronics

Authorized Distributor

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[International Rectifier:](#)

[IR3629AMTRPBF](#) [IR3629MTRPBF](#)